VS-E4PH6006LHN3

Vishay Semiconductors



Hyperfast Soft Recovery Diode, 60 A FRED Pt[®] Gen 4



PRODUCT SUMMARY							
Package	TO-247AD 2L						
I _{F(AV)}	60 A						
V _R	600 V						
V _F at I _F	1.48 V						
t _{rr} typ.	see Recovery table						
T _J max.	175 °C						
Diode variation	Single die						

FEATURES

- Gen 4 FRED Pt[®] technology
- Low I_{RRM} and reverse recovery charge
- Very low forward voltage drop
- Polyimide passivated chip for high reliability standard
- 175 °C operating junction temperature
- AEC-Q101 qualified, meets JESD 201 class 1 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

Gen 4 Fred technology, state of the art, ultralow V_F, soft switching optimized for Discontinuous (Critical) Mode (DCM) and IGBT F/W diode.

The minimized conduction loss, optimized stored charge and low recovery current minimized the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS				
Cathode to anode voltage	V _R		600	V				
Average rectified forward current	I _{F(AV)}	T _C = 106 °C	60	٨				
Single pulse forward current	I _{FSM}	T_C = 25 °C, t_p = 8.3 ms, half sine wave	425	A				
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C				

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	600	-	-			
		I _F = 50 A	-	1.68	-			
		I _F = 60 A	-	1.75	2.0	V		
Forward voltage	V _F	I _F = 50 A, T _J = 125 °C	-	1.44	-			
Forward voltage		I _F = 60 A, T _J = 125 °C	-	1.55	-			
		I _F = 50 A, T _J = 150 °C	-	1.39	-			
		I _F = 60 A, T _J = 150 °C	-	1.48	1.65			
	I _R	$V_{R} = V_{R}$ rated	-	-	50			
Reverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA		
Junction capacitance	CT	V _R = 600 V	-	30	-	pF		

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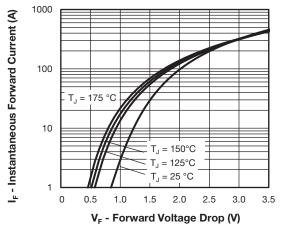


COMPLIANT HALOGEN



DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST C	MIN.	TYP.	MAX.	UNITS				
Reverse recovery time	+	T _J = 25 °C		-	68	-	ns			
Reverse recovery time	t _{rr}	T _J = 125 °C	I _F = 60 A dI _F /dt = 1000 A/μs V _B = 400 V	-	92	-				
De als vera assert	I _{RRM}	T _J = 25 °C		-	20	-	Α			
Peak recovery current		T _J = 125 °C		-	40	-	A			
Reverse recovery charge	Q _{rr}	T _J = 25 °C	V _R = 400 V	-	945	-	nC			
		T _J = 125 °C		-	2500	-	IIC IIC			

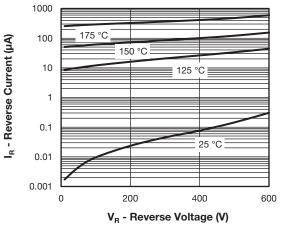
THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Thermal resistance, junction to case	R _{thJC}		-	-	0.6	°C/W				
Thermal resistance, case to heat sink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.25	-					
Walaht			-	6.0	-	g				
Weight			-	0.21	-	oz.				
Mounting torque			6.0		12	kgf · cm				
			(5)	-	(20)	(lbf · in)				
Marking device		Case style TO-247AD 2L	E4PH6006LH							



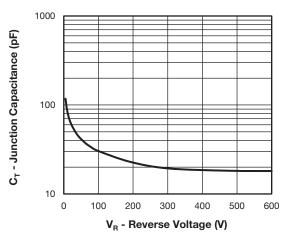
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Fig. 1 - Typical Forward Voltage Drop Characteristics





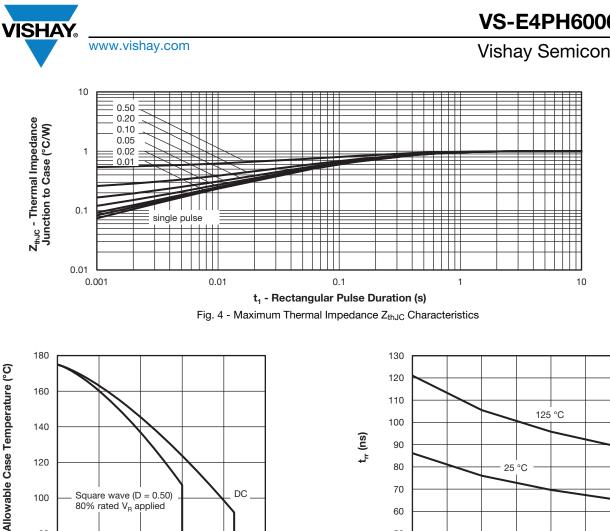


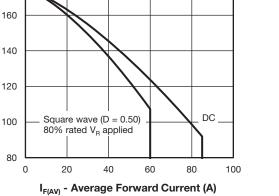


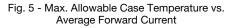
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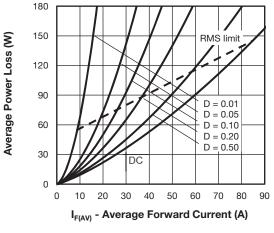
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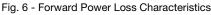
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Note

Formula used: $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$; (1)

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \, x \, \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{Fig.5}) \\ \mathsf{P}_{\mathsf{d}\mathsf{R}\mathsf{EV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R}1} \, x \, \mathsf{I}_{\mathsf{R}} \ (1 - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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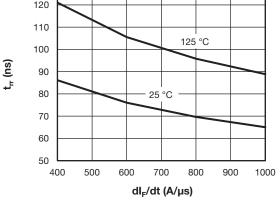


Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

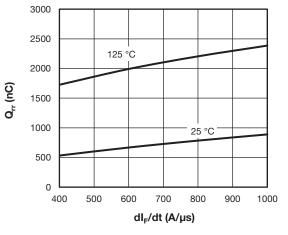


Fig. 8 - Typical Stored Charge vs. dl_F/dt

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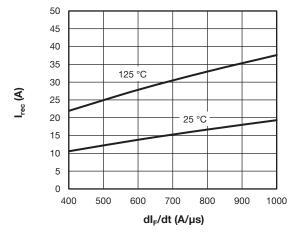


Fig. 9 - Typical Reverse Recovery vs. dl_F/dt

ORDERING INFORMATION TABLE

Device code	VS-	Е	4	Р	Н	60	06	L	Н	N3
	1	2	3	4	5	6	7	8	9	(10)
	1 -	· Visł	nay Serr	niconduc	tors pro	oduct				
	2 -	· Circ	Circuit configuration:							
		E =	E = single diode 2 pins							
	3 -	FRE	FRED Gen 4							
	4 -	• P=	TO-247	packag	е					
	5 -	- Pro	cess typ	be:						
		H =	Hyperfa	ast reco	very					
	6 -	- Cur	rent rati	ng (60 =	60 A)					
	7 -	· Volt	age rati	ng (06 =	600 V)					
	8 -	- L=	L = long lead							
	9 -	• H=	H = AEC-Q101 qualified							
	10 -			ntal digit: en-free,		ompliar	nt, and t	otally le	ad (Pb)	-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-E4PH6006LHN3	25	500	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS						
Dimensions	TO-247AD 2L	www.vishay.com/doc?95536				
Part marking information	TO-247AD 2L	www.vishay.com/doc?95648				

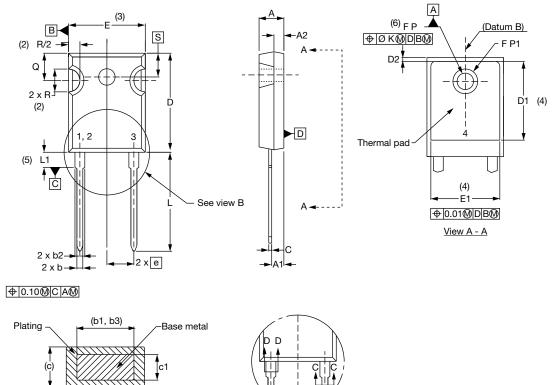
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TO-247AD 2L

DIMENSIONS in millimeters and inches



Section C - C, D - D

MILLIMET

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MIN.

4.65

2.21

1.50 0.99

0.99

1.65

1.65

0.38 0.38

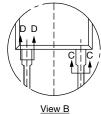
19.71

13.08

0.51

(b, b2)

(4)



TERS	INC	HES	NOTES	NOTES			SYMBOL	MILLIN	IETERS	INC	NOTES
MAX.	MIN.	MAX.	NUTES		STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
5.31	0.183	0.209			E	15.29	15.87	0.602	0.625	3	
2.59	0.087	0.102			E1	13.46	-	0.53	-		
2.49	0.059	0.098			е	5.46	BSC	0.215 BSC			
1.40	0.039	0.055			ØK	0.254 0.010)10			
1.35	0.039	0.053			L	19.81	20.32	0.780	0.800		
2.39	0.065	0.094			L1	3.71	4.29	0.146	0.169		
2.34	0.065	0.092			ØР	3.56	3.66	0.14	0.144		
0.89	0.015	0.035			Ø P1	-	6.98	-	0.275		
0.84	0.015	0.033			Q	5.31	5.69	0.209	0.224		
20.70	0.776	0.815	3		R	4.52	5.49	0.178	0.216		
-	0.515	-	4		S	5.51	BSC	0.217	BSC		

Notes

SYMBOL

A A1

A2

b

b1 b2

b3

С

c1 D

D1

D2

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

1.35

0.020

0.053

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

(5) Lead finish uncontrolled in L1

(6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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